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Key indicators

Single-crystal X-ray study
 T = 294 K
 Mean σ (C–C) = 0.006 Å
 R factor = 0.079
 wR factor = 0.085
 Data-to-parameter ratio = 19.6

For details of how these key indicators were
 automatically derived from the article, see
<http://journals.iucr.org/e>.

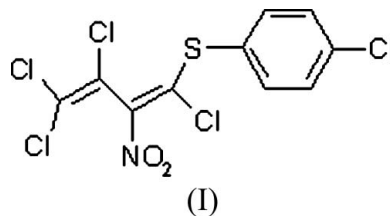
**1,3,4,4-Tetrachloro-4-(4-chlorophenyl-
 sulfanyl)-2-nitrobuta-1,3-diene**

The molecule of the title compound, C₁₀H₄Cl₅NO₂S, is not planar. The chlorophenyl ring and the butadiene group are inclined at an angle of 59.5 (1)°.

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Comment

The chemistry of nitro compounds, especially their halogen derivatives, has been intensively studied in recent decades. These highly reactive substances have been used to develop preparative methods for the synthesis of complex polyfunctional derivatives of different classes. However, there are only a few reports on the crystal structures of halogenated nitrobutadiene compounds. The title compound, (I), was synthesized from 2-nitropentachlorobutadiene and *p*-chlorothiophenol (Ibis & Goksel, 1994). Crystallographic analysis was carried out and the results are presented in this paper.



The molecule is not planar. The chlorophenyl ring and the butadiene group are inclined at an angle of 59.5 (1)°. The C–C bond lengths of the butadiene chain agree well with corresponding distances in a similar compound (Surange *et al.*, 1997).

Experimental

p-Chlorothiophenol (1.06 g, 7.37 mmol) and 2-nitropentachloro-1,3-butadiene (2 g, 7.37 mmol) were stirred for 24 h at room temperature. The product was extracted with chloroform; the organic layer was separated and washed with distilled water (3 × 30 ml) and dried with Na₂SO₄. The solvent was evaporated and the residue was purified by crystallization from ethanol (yield: 2.2 g, 79%; m.p. 386–388 K).

Crystal data

C₁₀H₄Cl₅NO₂S
 M_r = 379.46
 Triclinic, P $\bar{1}$
 a = 6.6504 (4) Å
 b = 10.7872 (3) Å
 c = 10.857 (4) Å
 α = 70.481 (4)°
 β = 87.411 (8)°
 γ = 83.680 (7)°
 V = 729.6 (3) Å³

Z = 2
 D_x = 1.727 Mg m⁻³
 Mo Kα radiation
 Cell parameters from 6436 reflections
 θ = 3.1–30.1°
 μ = 1.13 mm⁻¹
 T = 293.5 K
 Block, yellow
 0.40 × 0.30 × 0.25 mm

Data collection

Rigaku R-AXIS RAPID
diffractometer
 ω scans
Absorption correction: multi-scan
(*ABSCOR*; Higashi, 1995)
 $T_{\min} = 0.677$, $T_{\max} = 0.760$
8204 measured reflections

4303 independent reflections
3450 reflections with $F^2 > 2\sigma(F^2)$
 $R_{\text{int}} = 0.021$
 $\theta_{\text{max}} = 30.1^\circ$
 $h = -9 \rightarrow 9$
 $k = -14 \rightarrow 15$
 $l = -15 \rightarrow 15$

Refinement

Refinement on F
 $R[F^2 > 2\sigma(F^2)] = 0.079$
 $wR(F^2) = 0.085$
 $S = 1.10$
3450 reflections
176 parameters
H-atom parameters constrained

Chebyshev polynomial with three
parameters (Carruthers &
Watkin, 1979): 9.9084, 2.2048
and 6.4348
 $(\Delta/\sigma)_{\text{max}} = 0.009$
 $\Delta\rho_{\text{max}} = 1.24 \text{ e } \text{\AA}^{-3}$
 $\Delta\rho_{\text{min}} = -0.77 \text{ e } \text{\AA}^{-3}$

Table 1

Selected geometric parameters (\AA , $^\circ$).

C1–C2	1.285 (8)	C3–C4	1.354 (5)
C2–C3	1.478 (5)		
C3–C2–C1	122.8 (4)	C4–C3–C2	125.1 (4)

H atoms were treated as riding, with C–H = 0.95 (6) \AA and $U_{\text{iso}}(\text{H}) = 1.2U_{\text{eq}}(\text{C})$. The maximum electron-density peak is located 0.62 \AA from atom C13.

Data collection: *CRYSTALCLEAR* (Rigaku/MS, 2002); cell refinement: *CRYSTALCLEAR*; data reduction: *CrystalStructure* (Rigaku/MS, 2003); program(s) used to solve structure: *SIR92* (Altomare *et al.*, 1994); program(s) used to refine structure: *CRYSTALS* (Betteridge *et al.*, 2003); molecular graphics: *ORTEP-3* (Farrugia, 1997); software used to prepare material for publication: *CrystalStructure*.

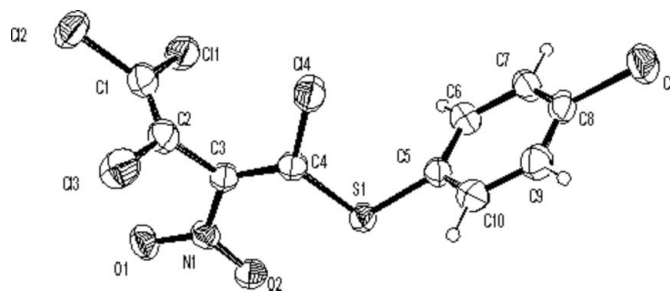


Figure 1

The molecular structure of the title compound. Displacement ellipsoids are drawn at the 50% probability level.

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